

The Structures of the Reduced and Oxidized Forms of Barium Silicon Tantalum Oxide, $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{23}$ and $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{26}$

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The compound once reported as $\text{Ba}_{0.5-x}\text{TaO}_{3-x}$ has now been shown to be $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{23}$. The silicon is readily introduced from the silica reaction capsule if fluoride is present. The symmetry is hexagonal, space group $P\bar{6}2m$, $a = 8.997 \pm 0.003$, $c = 7.745 \pm 0.005$ Å. The structure contains layers with tantalum coordinated by a square pyramid of oxygens and silicon coordinated tetrahedrally by oxygens. These layers are mirrored to form double layers which are interleaved with barium ions. The oxidized phase, $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{26}$, which may be formed by oxidation of the reduced phase, has the same space group, and cell dimensions $a = 8.99 \pm 0.01$, $c = 7.79 \pm 0.01$ Å. The additional oxygens complete octahedra about the tantalum atoms.

Introduction

A previous attempt at the determination of the structure of $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{23}$ was made on the assumption that the formula was $\text{Ba}_{0.5-x}\text{TaO}_{3-x}$ (1). Some discussion is offered in succeeding sections of this paper to explain how it was possible for members of a chemistry department to have made this error in the composition. In the earlier work a trial structure was obtained with a unit cell formula of $\text{Ba}_3\text{Ta}_6\text{O}_{18}$. Although there was fair agreement between calculated and observed structure factors for the available data, the following points were cited as disturbing: (1) There were marked deviations from Pauling's electrostatic valency rules. (2) There was no explanation for the observed Ba:Ta ratio of 0.44. (3) The maximum of 18 oxygens left considerable unfilled volume. (4) The X-ray density was lower than the observed range of values. It was indicated that at some future time a systematic effort would, hopefully, be undertaken to resolve the difficulties. This has now been accomplished. In addition the oxidized phase has also been studied and the locations of the added oxygens have been found.

Experimental

Reduced Phase

The reduced phase was first prepared by using BaO, a Fairmount sample of Ta_2O_5 , and Ta metal

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in the mole ratios 5:4:2 and heated at 1250°C in an evacuated, sealed, silica capsule for 24 h. A blue product covered with blue hexagonal crystals was formed. The size of the crystals could be increased by wrapping the sample in Ta foil before heating. However, when new samples of Fansteel and Fairmount Ta_2O_5 were used, the hexagonal compound was not obtained. Instead a tetragonal compound was found. It seemed the hexagonal phase could only be prepared when Ta_2O_5 from a particular bottle was used, and when that source was exhausted, only the tetragonal phase could be prepared. Eventually, it was found that with very long heating at 1250°C or by using Ta_2O_5 dissolved by sodium hydroxide fusion and reprecipitated some of the hexagonal phase could be obtained. A still more successful preparation involved the use of BaCl_2 as a flux, but the product was still not homogeneous.

Suspicion that the original Ta_2O_5 had contained a fluoride impurity led us to add some BaF_2 to the reaction mixture. When this was done the hexagonal phase was obtained much more readily and with greater homogeneity.

The sample of reduced phase from which the crystal studied was taken was prepared by mixing $5\text{BaO}:4\text{Ta}_2\text{O}_5:1\text{Ta}$ with 5% BaF_2 by weight. The mixture was pressed into pellets, wrapped in Ta foil, sealed in evacuated silica capsules, and heated for three days at 1250°C. Clear blue flat crystals were found on the surface of the pellet, on the foil, and on the capsule. Another heating cycle improved the

TABLE I
REPRESENTATIVE ABSORPTION CORRECTIONS

<i>hkl</i>	<i>I</i> measured	Transmission factor	Relative FOBS
400	112	0.085	249
440	97	0.071	274
040	190	0.145	265
310	64	0.090	113
430	86	0.085	117
140	112	0.139	106
611	17	0.093	82
761	13	0.085	75
171	20	0.140	73
442	179	0.113	256
842	154	0.098	254
482	183	0.110	262
324	132	0.113	192
534	130	0.180	195
254	154	0.137	188
507	25	0.124	97
557	37	0.174	122
057	34	0.143	100
4110	7	0.193	57
5410	6	0.160	53
1510	6	0.154	48

homogeneity of the sample. Although most of the crystals were twinned, a thin plate was found to be single and was cut to an approximately rectangular parallelepiped, $0.055 \times 0.055 \times 0.042$ mm.

Precession photography of the zero and first levels with the X-ray beam normal to the plate showed the crystal to be hexagonal, Laue group $6/mmm$. Further examination revealed no systematic absences, so the probable space group was one of $P622$, $P6mm$, ($P\bar{6}m2$, $P\bar{6}2m$), or $P6/mmm$. Structure considerations eliminated the space groups with sixfold axes almost immediately and later established the probable space group as $P\bar{6}2m$. Cell dimensions were calculated from measurements on a G.E. single crystal orienter: $a = 8.997$ (3), $c = 7.745$ (5) Å.

All reflections for which $k \geq 0$, $h \geq k$ for $l = 0$ through $l = 12$ up to $2\theta = 60^\circ$ were measured on a G.E. single-crystal orienter with Zr filtered Mo radiation, pulse height discrimination, 2° take off angle, and scintillation counter. The θ , 2θ scan technique was used at 2° $2\theta/\text{min}$ for 80 sec. Background was measured by stationary counting at both ends of the 2.67° range. The total number of reflections measured was 1527 which yielded 509 independent reflections of which 254 were greater than 2σ for the background.

Because μ_l is about 478 for Mo radiation and μR is about 2.6, serious absorption problems are encountered. Symmetry related intensities were found in some cases to differ by as much as a factor of two. To correct for absorption, the crystal was measured with a travelling microscope and its shape described by six bounding planes. The absorption corrections were then made using Prewitt's program ACACA (2) by integration over an $8 \times 8 \times 4$ grid. Table I shows representative absorption corrections and illustrates how dramatic the absorption effect can sometimes be. The reflections in the table are symmetry related in sets of three, but this isn't always obvious from the raw intensities.

Oxidized Phase

Crystals of the oxidized phase were clear colorless plates formed by heating crystals of the reduced phase in air at 1000°C for 1 h. The only single crystals obtained were thin plates. One of these was cut to a rectangle $0.2 \times 0.2 \times 0.003$ mm and mounted with a^* parallel to the fiber. To obtain a measurable intensity and small absorption for low values of l this orientation was much better than one with c in the fiber direction because of the shape of the crystal.

The probable space group is the same as for the reduced phase, $P\bar{6}2m$. Cell dimensions are $a = 8.99$ (1), $c = 7.79$ (1) Å. Reflections were measured in the same way as for the reduced phase, for $l = 0$ through $l = 4$ and $2\theta \leq 60^\circ$. A total of 518 measurements yielded 258 independent reflections of which 179 were greater than 2σ for the background. Absorption corrections were applied (as for the reduced phase) with the crystal described by six bounding planes and integration performed over an $8 \times 8 \times 4$ grid.

Structure Determination

Reduced Phase

Three bariums and six tantalums were placed in the positions postulated in the earlier structure work (1). Four cycles of least-squares refinement (3) lowered the R factor from 33.0 to 12.8%. Inclusion of the oxygens in the positions of the trial structure lowered R to 10.7%, but when atom multipliers for the oxygens were varied, the multiplier for the oxygen at 0.24, 0, and 0.5 became negative. This oxygen completes an octahedron around tantalum, so its absence would mean that there are only five oxygens coordinated to tantalum. A difference

Fourier (4) based on phases determined by barium and tantalum not only confirmed the absence of this oxygen but produced a sharp peak at $\frac{1}{3}, \frac{2}{3}, 0.24$ and a broader peak at $\frac{1}{3}, \frac{2}{3}, 0$. The first of these sites was a reasonable location for additional tantalum, but previous attempts to place tantalum there had led to worsened structure factor agreement (5). Nevertheless, because of the sharp peak produced on the difference map, tantalum was again tried at this position, but with a variable atom multiplier in a least-squares refinement. The multiplier converged to 0.063 (full occupancy = 0.333) which corresponds very nearly to atomic number 14 and immediately suggested silicon. The other, broader, peak suggested oxygen. Isotropic refinement with these additional atoms in the structure (anomalous dispersion corrections included) reduced R to 8.4%. Changing the sign of $\Delta f''$ and refining increased R to 9.3%, which indicated the original choice of indexing to be correct. A Hughes-type weighting scheme (6) with $\sqrt{w} = 1$ for $|F_{\text{obs}}| \leq 4|F_{\text{min}}|$ and $\sqrt{w} = 4|F_{\text{min}}|/|F_{\text{obs}}|$ for $|F_{\text{obs}}| > 4|F_{\text{min}}|$ with $F_{\text{min}} = 50$ was then introduced, and isotropic refinement led to a final value for $R \equiv \Sigma||F_0| - k|F_c|| / \Sigma|F_0| = 0.077$ and weighted $R \equiv [\Sigma\omega(|F_0| - k|F_c|)^2 / \Sigma\omega|F_0|^2]^{1/2} = 0.100$. Anisotropic refinement yielded position parameters which were not significantly different from the isotropic results and thermal parameters which were physically improbable, so the results of the anisotropic refinement are not reported here. A final difference Fourier showed no peaks greater than $\frac{1}{8}$ of an oxygen peak. A final attempt to place another oxygen in the position which would complete the octahedron around

tantalum was tested by least squares with a variable atom multiplier; the multiplier actually became somewhat negative, emphasizing the absence of any atom at this position.

Scattering factors for O¹⁻ and Si²⁺ (by interpolation) were obtained from the International Tables (7). The values for Ba¹⁺ and Ta²⁺ were obtained from Thomas and Umeda (8). Anomalous dispersion corrections were obtained from Cromer (9).

Final atomic positions and temperature factors are listed in Table II, observed and calculated structure factors in Table III.

Oxidized Phase

Refinement of the oxidized phase began with the parameters of the reduced phase. It was found that R was reduced from 8.6–7.6% by making $\Delta f''$ negative; accordingly the hkl data were re-indexed as $\bar{h}\bar{k}l$. The possible positions for the additional oxygen of the oxidized phase were 0.21, 0, $\frac{1}{2}$ and $\frac{1}{3}, \frac{2}{3}, \frac{1}{2}$; both gave about the same R factor. However, the temperature factor for the first position was better behaved, since it remained low, whereas after four cycles it increased to about 7 for the second position. The Fourier evidence was stronger; a difference Fourier assuming oxygen in the 0.21, 0, $\frac{1}{2}$ position but absent from the $\frac{1}{3}, \frac{2}{3}, \frac{1}{2}$ position showed no peaks greater than $\frac{1}{10}$ of an oxygen peak.

Weights for the least-squares refinement were then assigned as with the reduced phase but with $F_{\text{min}} = 58$. The final conventional R was 7.3% (weighted $R = 9.6\%$).

TABLE II
ATOMIC POSITIONS AND THERMAL PARAMETERS FOR Ba₃Si₄Ta₆O₂₃^a SPACE GROUP No. 189,
P62m

Atom	Position	<i>x</i>	<i>y</i>	<i>z</i>	<i>B</i> × 10 ²
Ba	3 <i>g</i>	0.6016 (8)	0	$\frac{1}{3}$	49 (9)
Ta	6 <i>i</i>	0.2384 (3)	0	0.2428 (4)	36 (4)
Si	4 <i>h</i>	$\frac{1}{3}$	$\frac{2}{3}$	0.2046 (31)	16 (33)
O(I)	2 <i>c</i>	$\frac{1}{3}$	$\frac{2}{3}$	0	154 (204)
O(II)	3 <i>f</i>	0.2919 (111)	0	0	93 (163)
O(III)	6 <i>i</i>	0.8191 (59)	0	0.2363 (68)	22 (72)
O(IV)	12 <i>l</i>	0.4939 (48)	0.1773 (46)	0.2802 (36)	33 (57)

Position 2*c*: $\frac{1}{3}, \frac{2}{3}, 0; \frac{2}{3}, \frac{1}{3}, 0$. 3*f*: *x*, 0, 0; 0, *x*, 0; $\bar{x}, \bar{x}, 0$. 3*g*: *x*, 0, $\frac{1}{3}$; 0, *x*, $\frac{1}{3}$; $\bar{x}, \bar{x}, \frac{1}{3}$. 4*h*: $\frac{1}{3}, \frac{2}{3}, z; \frac{2}{3}, \frac{1}{3}, \bar{z}; \frac{1}{3}, \frac{2}{3}, z; \frac{2}{3}, \frac{1}{3}, \bar{z}$. 6*i*: *x*, 0, *z*; 0, *x*, *z*; $\bar{x}, \bar{x}, z; x, 0, \bar{z}; 0, x, \bar{z}; \bar{x}, \bar{x}, \bar{z}$. 12*l*: *x*, *y*, *z*; $\bar{x}, y, z; y - x, \bar{x}, z; x, y, \bar{z}; \bar{y}, x - y, \bar{z}; y - x, \bar{x}, \bar{z}; y, x, z; \bar{x}, y - x, z; x - y, \bar{y}, z; y, x, \bar{z}; \bar{x}, y - x, \bar{z}; x - y, \bar{y}, z$.

^a Standard deviations, as calculated by ORFLS, are given in parentheses.

TABLE III. OBSERVED AND CALCULATED STRUCTURE FACTORS, REDUCED PHASE (The columns are h , k , $|F_0|$, and $|F_c|$)

h	k	$ F_0 $	$ F_c $
1	0	121 99	0 0 < 73 105
2	0	147 169	2 0 < 99 98
3	0	237 254	3 0 < 148 135
4	0	< 56 14	5 0 < 117 105
5	0	< 64 41	6 0 < 59 22
6	0	223 226	7 0 71 40
7	0	185 191	8 0 66 30
8	0	177 195	9 0 113 105
9	1	261 316	1 1 131 147
10	1	113 89	2 1 66 39
11	1	175 171	3 1 103 104
12	1	212 212	4 1 180 115
13	1	95 100	5 1 < 77 83
14	1	108 99	6 1 < 69 39
15	1	57 79	7 1 < 73 40
16	1	137 156	8 1 < 77 15
17	2	208 233	2 2 81 75
18	2	145 133	3 2 80 82
19	2	187 161	4 2 77 77
20	2	199 171	5 2 < 62 44
21	2	73 72	6 2 < 90 49
22	2	158 177	7 2 < 74 32
23	2	257 296	10 2 < 90 35
24	3	132 136	3 3 < 51 33
25	3	170 176	4 3 < 69 55
26	3	206 206	5 3 < 63 40
27	3	88 78	6 3 < 71 41
28	3	85 85	7 3 < 75 22
29	3	211 215	10 3 < 81 75
30	4	113 111	4 4 < 64 47
31	4	173 226	5 4 < 70 88
32	4	184 188	6 4 < 71 76
33	4	82 97	7 4 < 80 41
34	5	124 123	10 4 < 82 68
35	5	196 166	5 5 < 79 45
36	5	189 177	6 5 < 72 31
37	5	139 139	7 5 < 79 23
38	5	175 180	8 5 < 81 58
39	6	178 54	9 6 < 81 58
40	6	181 99	10 6 < 81 58
41	7	128 136	7 7 < 81 58
42	7	159 167	8 7 < 81 58
43	7	167 174	9 7 < 81 58
44	7	178 184	10 7 < 81 58
45	8	121 123	8 8 < 81 58
46	8	131 133	9 8 < 81 58
47	8	141 143	10 8 < 81 58
48	9	151 153	9 9 < 81 58
49	9	161 163	10 9 < 81 58
50	10	171 173	9 10 < 81 58
51	10	181 183	10 10 < 81 58
52	11	191 193	9 11 < 81 58
53	11	201 203	10 11 < 81 58
54	12	211 213	9 12 < 81 58
55	12	221 223	10 12 < 81 58
56	13	231 233	9 13 < 81 58
57	13	241 243	10 13 < 81 58
58	14	251 253	9 14 < 81 58
59	14	261 263	10 14 < 81 58
60	15	271 273	9 15 < 81 58
61	15	281 283	10 15 < 81 58
62	16	291 293	9 16 < 81 58
63	16	301 303	10 16 < 81 58
64	17	311 313	9 17 < 81 58
65	17	321 323	10 17 < 81 58
66	18	331 333	9 18 < 81 58
67	18	341 343	10 18 < 81 58
68	19	351 353	9 19 < 81 58
69	19	361 363	10 19 < 81 58
70	20	371 373	9 20 < 81 58
71	20	381 383	10 20 < 81 58
72	21	391 393	9 21 < 81 58
73	21	401 403	10 21 < 81 58
74	22	411 413	9 22 < 81 58
75	22	421 423	10 22 < 81 58
76	23	431 433	9 23 < 81 58
77	23	441 443	10 23 < 81 58
78	24	451 453	9 24 < 81 58
79	24	461 463	10 24 < 81 58
80	25	471 473	9 25 < 81 58
81	25	481 483	10 25 < 81 58
82	26	491 493	9 26 < 81 58
83	26	501 503	10 26 < 81 58
84	27	511 513	9 27 < 81 58
85	27	521 523	10 27 < 81 58
86	28	531 533	9 28 < 81 58
87	28	541 543	10 28 < 81 58
88	29	551 553	9 29 < 81 58
89	29	561 563	10 29 < 81 58
90	30	571 573	9 30 < 81 58
91	30	581 583	10 30 < 81 58
92	31	591 593	9 31 < 81 58
93	31	601 603	10 31 < 81 58
94	32	611 613	9 32 < 81 58
95	32	621 623	10 32 < 81 58
96	33	631 633	9 33 < 81 58
97	33	641 643	10 33 < 81 58
98	34	651 653	9 34 < 81 58
99	34	661 663	10 34 < 81 58
100	35	671 673	9 35 < 81 58
101	35	681 683	10 35 < 81 58
102	36	691 693	9 36 < 81 58
103	36	701 703	10 36 < 81 58
104	37	711 713	9 37 < 81 58
105	37	721 723	10 37 < 81 58
106	38	731 733	9 38 < 81 58
107	38	741 743	10 38 < 81 58
108	39	751 753	9 39 < 81 58
109	39	761 763	10 39 < 81 58
110	40	771 773	9 40 < 81 58
111	40	781 783	10 40 < 81 58
112	41	791 793	9 41 < 81 58
113	41	801 803	10 41 < 81 58
114	42	811 813	9 42 < 81 58
115	42	821 823	10 42 < 81 58
116	43	831 833	9 43 < 81 58
117	43	841 843	10 43 < 81 58
118	44	851 853	9 44 < 81 58
119	44	861 863	10 44 < 81 58
120	45	871 873	9 45 < 81 58
121	45	881 883	10 45 < 81 58
122	46	891 893	9 46 < 81 58
123	46	901 903	10 46 < 81 58
124	47	911 913	9 47 < 81 58
125	47	921 923	10 47 < 81 58
126	48	931 933	9 48 < 81 58
127	48	941 943	10 48 < 81 58
128	49	951 953	9 49 < 81 58
129	49	961 963	10 49 < 81 58
130	50	971 973	9 50 < 81 58
131	50	981 983	10 50 < 81 58
132	51	991 993	9 51 < 81 58
133	51	1001 1003	10 51 < 81 58
134	52	1011 1013	9 52 < 81 58
135	52	1021 1023	10 52 < 81 58
136	53	1031 1033	9 53 < 81 58
137	53	1041 1043	10 53 < 81 58
138	54	1051 1053	9 54 < 81 58
139	54	1061 1063	10 54 < 81 58
140	55	1071 1073	9 55 < 81 58
141	55	1081 1083	10 55 < 81 58
142	56	1091 1093	9 56 < 81 58
143	56	1101 1103	10 56 < 81 58
144	57	1111 1113	9 57 < 81 58
145	57	1121 1123	10 57 < 81 58
146	58	1131 1133	9 58 < 81 58
147	58	1141 1143	10 58 < 81 58
148	59	1151 1153	9 59 < 81 58
149	59	1161 1163	10 59 < 81 58
150	60	1171 1173	9 60 < 81 58
151	60	1181 1183	10 60 < 81 58
152	61	1191 1193	9 61 < 81 58
153	61	1201 1203	10 61 < 81 58
154	62	1211 1213	9 62 < 81 58
155	62	1221 1223	10 62 < 81 58
156	63	1231 1233	9 63 < 81 58
157	63	1241 1243	10 63 < 81 58
158	64	1251 1253	9 64 < 81 58
159	64	1261 1263	10 64 < 81 58
160	65	1271 1273	9 65 < 81 58
161	65	1281 1283	10 65 < 81 58
162	66	1291 1293	9 66 < 81 58
163	66	1301 1303	10 66 < 81 58
164	67	1311 1313	9 67 < 81 58
165	67	1321 1323	10 67 < 81 58
166	68	1331 1333	9 68 < 81 58
167	68	1341 1343	10 68 < 81 58
168	69	1351 1353	9 69 < 81 58
169	69	1361 1363	10 69 < 81 58
170	70	1371 1373	9 70 < 81 58
171	70	1381 1383	10 70 < 81 58
172	71	1391 1393	9 71 < 81 58
173	71	1401 1403	10 71 < 81 58
174	72	1411 1413	9 72 < 81 58
175	72	1421 1423	10 72 < 81 58
176	73	1431 1433	9 73 < 81 58
177	73	1441 1443	10 73 < 81 58
178	74	1451 1453	9 74 < 81 58
179	74	1461 1463	10 74 < 81 58
180	75	1471 1473	9 75 < 81 58
181	75	1481 1483	10 75 < 81 58
182	76	1491 1493	9 76 < 81 58
183	76	1501 1503	10 76 < 81 58
184	77	1511 1513	9 77 < 81 58
185	77	1521 1523	10 77 < 81 58
186	78	1531 1533	9 78 < 81 58
187	78	1541 1543	10 78 < 81 58
188	79	1551 1553	9 79 < 81 58
189	79	1561 1563	10 79 < 81 58
190	80	1571 1573	9 80 < 81 58
191	80	1581 1583	10 80 < 81 58
192	81	1591 1593	9 81 < 81 58
193	81	1601 1603	10 81 < 81 58
194	82	1611 1613	9 82 < 81 58
195	82	1621 1623	10 82 < 81 58
196	83	1631 1633	9 83 < 81 58
197	83	1641 1643	10 83 < 81 58
198	84	1651 1653	9 84 < 81 58
199	84	1661 1663	10 84 < 81 58
200	85	1671 1673	9 85 < 81 58
201	85	1681 1683	10 85 < 81 58
202	86	1691 1693	9 86 < 81 58
203	86	1701 1703	10 86 < 81 58
204	87	1711 1713	9 87 < 81 58
205	87	1721 1723	10 87 < 81 58
206	88	1731 1733	9 88 < 81 58
207	88	1741 1743	10 88 < 81 58
208	89	1751 1753	9 89 < 81 58
209	89	1761 1763	10 89 < 81 58
210	90	1771 1773	9 90 < 81 58
211	90	1781 1783	10 90 < 81 58
212	91	1791 1793	9 91 < 81 58
213	91	1801 1803	10 91 < 81 58
214	92	1811 1813	9 92 < 81 58
215	92	1821 1823	10 92 < 81 58
216	93	1831 1833	9 93 < 81 58
217	93	1841 1843	10 93 < 81 58
218	94	1851 1853	9 94 < 81 58
219	94	1861 1863	10 94 < 81 58
220	95	1871 1873	9 95 < 81 58
221	95	1881 1883	10 95 < 81 58
222	96	1891 1893	9 96 < 81 58
223	96	1901 1903	10 96 < 81 58
224	97	1911 1913	9 97 < 81 58
225	97	1921 1923	10 97 < 81 58
226	98	1931 1933	9 98 < 81 58
227	98	1941 1943	10 98 < 81 58
228	99	1951 1953	9 99 < 81 58
229	99	1961 1963	10 99 < 81 58
230	100	1971 1973	9 100 < 81 58
231	100	1981 1983	10 100 < 81 58
232	101	1991 1993	9 101 < 81 58
233	101	2001 2003	10 101 < 81 58
234	102	2011 2013	9 102 < 81 58
235	102	2021 2023	10 102 < 81 58
236	103	2031 2033	9 103 < 81 58
237	103	2041 2043	10 103 < 81 58
238	104	2051 2053	9 104 < 81 58
239	104	2061 2063	10 104 < 81 58
240	105	2071 2073	9 105 < 81 58

TABLE IV
ATOMIC POSITIONS AND THERMAL PARAMETERS FOR Ba₃Si₄Ta₆O₂₆
SPACE GROUP No. 189, *P* $\bar{6}$ 2*m*

Atom	Position	<i>x</i>	<i>y</i>	<i>z</i> ^a	<i>B</i> × 10 ^{2a}
Ba	3 <i>g</i>	0.6022 (10)	0	$\frac{1}{2}$	77 (13)
Ta	6 <i>i</i>	0.2379 (3)	0	0.2452 (11)	36 (5)
Si	4 <i>h</i>	$\frac{1}{2}$	$\frac{2}{3}$	0.2137 (81)	52 (54)
O(I)	2 <i>c</i>	$\frac{1}{2}$	$\frac{2}{3}$	0	2 (184)
O(II)	3 <i>f</i>	0.2767 (86)	0	0	-16 (142)
O(III) ^b	6 <i>i</i>	0.8332 (97)	0	0.2112 (171)	50
O(IV)	12 <i>l</i>	0.4881 (39)	0.1809 (38)	0.2903 (62)	-67 (52)
O(V)	3 <i>g</i>	0.2217 (111)	0	$\frac{1}{2}$	65 (157)

^a Large errors, particularly in *z* and *B*, are due to the limited data in *z* direction. See text.

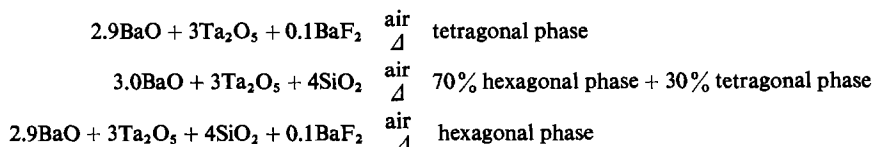
^b Multiplicity reduced to 0.7 of full occupancy value and *B* held fixed at 0.5. See text.

Final atomic positions and temperature factors are listed in Table IV, observed and calculated structure factors in Table V.

The refinement of the oxidized phase was in some respects unsatisfactory. Neither the temperature factor nor the *x* parameter of O(III) converged after eight cycles of isotropic refinement. In order to obtain convergence for the *x* parameter, the temperature factor was held fixed at 0.5 and the atom multiplier allowed to vary, with the results shown in Table IV. Other oxygen temperature factors are also unsatisfactory, and the errors in the *z* parameters are large. All of these difficulties are attributable to the limited data in *z*. This was established by calculating an electron density map with calculated structure factors as coefficients; this calculated Fourier showed wide variation in electron density at the oxygen positions with the lowest density at O(III). By extending the range of calculated structure factors to *l* = 12 instead of *l* = 4 the oxygen densities become equal and the map was altogether normal. The effect of the series truncation on the Fourier calculation suggests that the difficulties with the least squares refinement are also due to the limited data.

Chemical Evidence for Composition

The detection of silicon during the structure determination and a report of its presence in a commercial analysis (though no analysis was made for silicon) led to trying the following syntheses:



It was thus clear that the phase can be prepared with just the oxides of barium, tantalum, and silicon; that the fluoride is not essential to the preparation when SiO₂ is intimately mixed with the BaO and Ta₂O₅ (indeed, when care was taken to insure that the reactants were especially finely ground, by using agate mortar grinding and a SPEX mixer/mill, the hexagonal phase was formed with only minor impurities); but that even under these conditions, the fluoride aids the formation of the hexagonal compound. (The tetragonal phase was known from earlier work (10) and has the tetragonal tungsten bronze structure.)

Chemical analysis of the compound proved very difficult, particularly since the product was never completely homogeneous. The best analyses were probably those reported originally by Galasso in his thesis (11), but they were carried out at a time when the presence of silicon was not realized. In these analyses, SiO₂ would have come down with Ta₂O₅ and the total weight used (incorrectly, of course) to deduce the percentage of tantalum. The values calculated for Ba₃Si₄TaO₂₆: Ba, 20.34; Si, 5.55; Ta, 53.58. If the weighing forms for Ta and Si, Ta₂O₅, and SiO₂, respectively, were together mistakenly used to calculate Ta, the values calculated would be: Ba, 20.34, "Ta," 63.34. The found values: Ba, 20.98, "Ta," 61.64.

The difficulties in working with somewhat inhomogeneous products of course extended to the density determinations. These were performed on

TABLE V. OBSERVED AND CALCULATED STRUCTURE FACTORS, OXIDIZED PHASE (The columns are h , k , $|F_o|$, and $|F_c|$)

6	2	170	179	7	7	142	129	4	2	< 33	2	224	234	7	7	169	160	4	2	99	80	< 35	129							
2	2	123	116	5	2	< 44	44	3	2	< 40	36	2	194	142	6	2	< 43	42	3	2	< 31	50	2	139	161					
2	2	192	187	8	2	< 47	39	6	2	< 107	168	6	113	112	7	2	< 46	52	3	2	< 44	42	2	188	167					
4	0	99	96	3	5	306	311	0	0	311	323	9	2	75	99	0	0	142	142	8	2	< 65	43	8	140	147				
4	0	146	162	3	3	54	65	1	0	0	150	150	10	2	44	60	2	0	< 44	60	3	0	84	44	10	2	160	157		
4	0	234	224	3	3	122	135	2	0	0	140	192	3	3	208	211	3	0	84	83	4	3	< 33	62	3	3	267	263		
6	0	< 31	11	7	3	71	82	5	0	0	317	362	5	3	< 37	24	5	0	< 30	33	3	3	< 40	27	4	0	250	254		
7	0	49	34	6	3	71	82	5	0	0	317	362	5	3	< 37	24	5	0	< 30	33	3	3	< 40	27	4	0	218	224		
8	0	207	224	9	3	80	72	6	0	0	56	38	6	3	< 52	37	7	0	< 37	31	6	3	< 39	24	6	3	143	141		
10	0	142	135	5	4	259	208	0	0	0	32	2	8	7	225	229	7	0	< 37	31	6	3	< 39	24	6	3	178	180		
1	1	220	209	6	4	259	208	0	0	0	32	2	8	7	225	229	7	0	< 37	31	6	3	< 39	24	6	3	178	180		
2	1	338	350	6	4	170	170	10	0	0	56	67	10	3	100	94	9	0	< 43	19	10	3	< 54	30	9	0	203	209		
3	1	93	93	7	4	146	135	5	4	4	40	7	10	0	63	76	4	4	< 46	31	4	4	< 46	72	10	0	< 49	28		
5	1	178	183	8	4	131	132	2	1	1	337	323	5	4	151	162	2	1	109	109	2	4	< 44	34	4	4	210	111		
6	1	194	114	9	3	116	95	4	1	0	171	179	6	4	< 46	61	3	1	180	89	7	4	< 50	36	5	4	317	59		
6	1	102	114	9	3	116	95	4	1	0	171	179	6	4	< 46	61	3	1	180	89	7	4	< 50	36	5	4	317	59		
8	1	160	158	7	5	168	160	6	1	1	190	155	5	1	130	135	5	1	332	298	2	1	< 52	34	2	1	372	348		
8	1	102	114	9	3	116	95	4	1	0	171	179	6	4	< 46	61	3	1	180	89	7	4	< 50	36	5	4	317	59		
10	2	207	216	0	3	163	159	8	1	4	45	6	5	4	63	60	4	4	122	127	5	1	< 32	24	9	4	148	150		
3	2	228	228	6	4	195	184	10	1	1	54	62	6	5	154	139	8	1	< 51	56	7	5	< 54	74	6	1	92	94		
4	2	164	158	7	6	168	160	6	1	1	190	155	5	1	130	135	5	1	332	298	2	1	< 52	34	2	1	372	348		
4	2	192	174	8	6	101	87	3	2	2	121	105	7	6	80	73	3	2	48	10	6	6	< 56	23	3	2	219	161		

the reduced phase: $d_{calc} = 6.05 \text{ g/cm}^3$; $d_{obs} = 6.21 \text{ g/cm}^3$. The observed value reported here was a measurement on what appeared optically to be the cleanest preparation. However, we have obtained values as low as 5.74 g/cm^3 and as high as 6.29 g/cm^3 . These values straddle the theoretical one and attest to the difficulty of obtaining a single, clean, phase. In earlier work, presumably because particles of unreacted tantalum metal were present, some much higher densities were observed.

It is clear from the above that the chemical analyses and density information do not by themselves establish the formula. However, given the uncertainties involved, they are consistent with the results of the structure determination.

Discussion

Now that it is known that the phase originally written as $\text{Ba}_{0.44}\text{TaO}_{3-x}$ is, per unit cell, $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{23-26}$, the troublesome questions previously left unanswered (1) can be explained. The X-ray density is now in the range of observed values; there is no longer considerable unfilled volume, but indeed quite efficient packing; and there are no longer any unreasonably large deviations from Pauling's electrostatic valency rules. A comparison of sums of electrostatic bond strengths from adjacent cations for the oxidized model without silicon (idealized cell formula $\text{Ba}_3\text{Ta}_6\text{O}_{18}$), for the reduced compound (cell formula $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{23}$), and for the oxidized compound (cell formula $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{26}$) is presented in Table VI.

The early, but quite reproducible, chemical analyses resulting in the formula $\text{Ba}_{0.44}\text{TaO}_{3-x}$ deserve discussion. A great many complex metal oxides, including some of barium and tantalum, have been prepared in silica capsules without the silica behaving as a reagent. The present analyses were carried out assuming only barium, tantalum, and oxygen in the structure. The procedure used was fusion with potassium hydroxide in a silver crucible, cooling, immersion in dilute hydrochloric acid, at which time hydrous tantalum pentoxide precipitated out. Sulfuric acid was added to the solution and the barium determined as barium sulfate. Unfortunately, at the same time that the hydrous tantalum pentoxide precipitated, some hydrated silica would also precipitate (12). The result would be the calculation of a too high percentage of tantalum in the sample.

The question as to why silica should have reacted in these cases when in so many other preparations of complex metal oxides carried out in evacuated

TABLE VI
ELECTROSTATIC VALENCE SUMS FOR $Ba_3Ta_6O_{18}$, $Ba_3Si_4Ta_6O_{23}$,
AND $Ba_3Si_4Ta_6O_{26}$

Contribution from		Ba	Si	Ta	Total
2O	I	—	—	—	—
	II	—	2	—	2
	III	—	2	—	2
3O(II)	I	—	—	$1\frac{1}{3}$	$1\frac{1}{3}^a$
	II	—	—	$1\frac{1}{3}$	$1\frac{1}{3}$
	III	—	—	$1\frac{1}{3}$	$1\frac{1}{3}$
6O(III)	I	$\frac{1}{2}$	—	$1\frac{1}{3}$	$1\frac{1}{3}^a$
	II	$\frac{1}{2}$	—	$1\frac{1}{3}$	$1\frac{1}{3}$
	III	$\frac{1}{2}$	—	$1\frac{1}{3}$	$1\frac{1}{3}^a$
12O(IV)	I	$\frac{2}{3}$	—	$\frac{5}{6}$	$1\frac{7}{30}^a$
	II	$\frac{2}{3}$	1	$\frac{4}{3}$	$2\frac{1}{2}$
	III	$\frac{2}{3}$	1	$\frac{5}{6}$	$2\frac{7}{6}$
3O(V)	I	—	—	$1\frac{1}{3}$	$1\frac{1}{3}^a$
	II	—	—	—	—
	III	—	—	$1\frac{1}{3}$	$1\frac{1}{3}$

I, $Ba_3Ta_6O_{18}$; II, $Ba_3Si_4Ta_6O_{23}$; III, $Ba_3Si_4Ta_6O_{26}$.

^a Only 18 oxygens would be available to distribute among the 24 sites of these positions.

silica capsules it did not is of considerable interest. It has already been mentioned that this was dependent on the sample of Ta_2O_5 used. It is suspected now that the Ta_2O_5 used by Galasso in his initial preparations contained a fluoride impurity which resulted in the transport of silica from the capsule walls. Certainly, as reported in the experimental section, the addition of fluoride to the preparation mixture makes it easy to prepare the compound. Fluoride could well have been present, since, in the separation of niobium from tantalum, the dissolution of Nb_2O_5 - Ta_2O_5 mixtures in 70% HF is a common first step (13). Indeed, spectroscopically pure Nb_2O_5 has been shown in a dramatic way to sometimes contain fluoride impurity, since the structure of Nb_3O_7F was carried out on a crystal taken from a bottle of "spectroscopically pure" Nb_2O_5 (14)! It is reasonable to conclude that some samples of Ta_2O_5 would also contain fluoride impurity, introduced, ironically enough, in the process designed to purify the compound.

A commercial analysis of a sample prepared with fluoride deliberately added to facilitate the preparation showed about 1% fluoride. However, there is no evidence that the fluoride is actually incorporated in the structure.

A structural feature of interest is the value of the Si-O-Si angle (15)-(17). Since the oxygen positions

are not accurately determined in the present studies, it would ordinarily be expected that the Si-O-Si angle would not be known accurately. However, in our model all three atoms lie on a $\bar{6}$ axis, so that the angle is required to be 180° . This result would follow for any hexagonal space group, so the question is are we really sure the crystal is hexagonal. Optical evidence with the polarizing microscope indicates that the crystals are uniaxial (18), so, unless we are dealing with one of the uncommon exceptions (a possibility of course), we may reinforce our conclusion that the crystals are hexagonal. Then the only way to avoid the conclusion that the Si-O-Si angle is 180° would be to hold that the symmetry is statistical in nature. If one relaxed the symmetry requirement altogether, one could, of course, change the value for the Si-O-Si angle too. An estimate of standard deviations for the non-absorption corrected data suggests that this angle error could be 10 - 15° , or the angle could be about 165° . We have no evidence for any such relaxation of symmetry nor for statistical symmetry, so we have no reason to report an angle different from 180° . The possibility of linearity in a Si-O-Si bond has been questioned by Liebau (15) and supported by Cruickshank (16). Linear bonds have been reported in hexagonal $CaAl_2Si_2O_8$ (19) and in thortveitite (20). In both of these cases linearity is fixed by symmetry, but of course the symmetry decision itself can be called into question.

In projection down the c axis $Ba_3Si_4Ta_6O_{23-26}$ is very similar to $K_3V_5O_{14}$ (21), with Ba, Si, and Ta in the K , V_1 , and V_2 positions, respectively.† The coordination schemes are also similar, with trigonal pyramids around the V_1 atoms and square pyramids around the V_2 atoms. However, in the vanadium compound there are single layers interleaved with large cations (K^+), whereas in the tantalum compound there are double layers—one mirroring the other—and these double layers are interleaved with large cations (Ba^{++}). In the oxidized tantalum compound the square pyramids become octahedra with the addition of oxygens at the barium level. Tantalum-oxygen distances are in agreement with reported values. The tantalum atoms in the square pyramids lie very nearly at the base of the pyramid, whereas in $K_3V_5O_{14}$ the vanadium is reported to be markedly displaced towards the apex, although

† Dr. F. Galasso and I. (L. K.) discussed this problem with Dr. A. D. Wadsley on one of his visits to the University of Connecticut. On the basis of unit cell dimensions, probable cell contents, and an early Patterson map, Wadsley suggested that the structure should have much in common with that of $K_3V_5O_{14}$, as has now indeed been established.

in the latter case oxygens were placed from spatial considerations. Five coordinate tantalum has not been reported in the solid state, although trigonal bipyramidal coordination is reported for the vapor state pentahalides (22). Interatomic distances and angles are summarized in Table VII. Figures 1, 2, 3, 4, and 5 show, respectively, the tantalum environment in the reduced phase, the tantalum environment in the oxidized phase, a schematic drawing of four unit cells in *c* axis projection, and unit cell contents for the reduced and oxidized phases (23). The schematic drawing emphasizes the four connected net discussed by Wells (24). The rings of three tantalum polyhedra sharing corners, which are a feature of $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{23-26}$, are also found in the

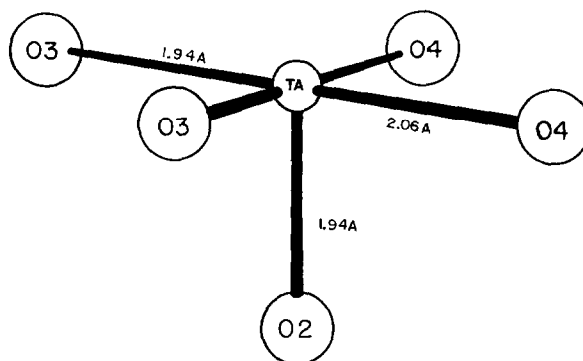


FIG. 1. Tantalum environment, reduced phase.

TABLE VII

DISTANCES AND ANGLES IN $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{23}$

Distances			
Ba-O(III)	2.83(5) Å	Ta-Ta	3.71(1); 3.76(1); 3.98(1)
Ba-O(IV)	2.82(4); 3.04(4)	O(I)-O(IV)	2.63(3)
Ta-O(II)	1.94(3)	O(II)-O(III)	2.94(7)
Ta-O(III)	1.94(2)	O(II)-O(IV)	2.77(5)
Ta-O(IV)	2.06(4)	O(III)-O(III)	2.82(9)
Si-O(I)	1.59(2)	O(III)-O(IV)	2.84(5)
Si-O(IV)	1.60(4)	O(IV)-O(IV)	2.57(6); 2.76(7)
Angles			
O(I)-Si-O(IV)	111.5(14)°	O(III)-Ta-O(III)	90.9(17)
O(IV)-Si-O(IV)	107.3(15)	O(III)-Ta-O(IV)	84.2(22)
O(II)-Ta-O(III)	98.3(25)	O(IV)-Ta-O(IV)	93.3(30)
O(II)-Ta-O(IV)	87.4(23)		

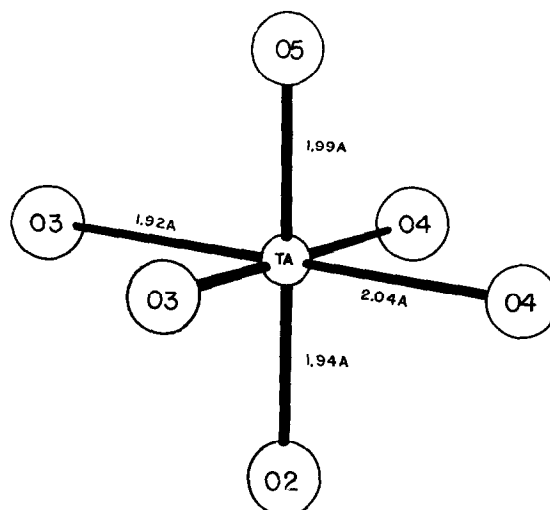
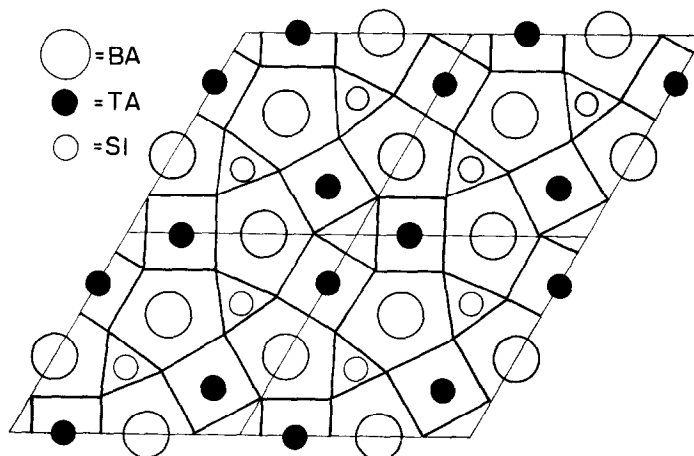


FIG. 2. Tantalum environment, oxidized phase.

FIG. 3. Schematic projection down *c* axis.

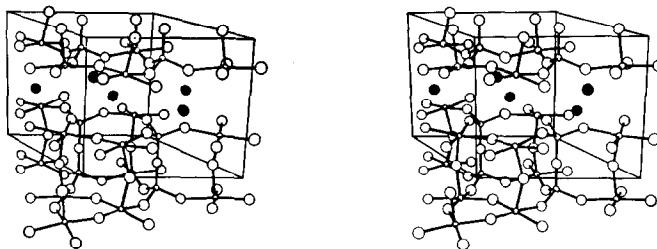


FIG. 4. Stereo view of unit cell contents, reduced phase.

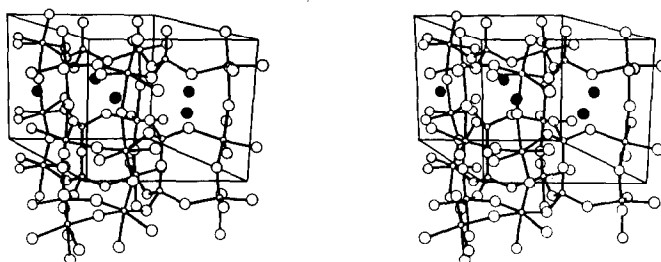


FIG. 5. Stereo view of unit cell contents, oxidized phase. Small open circles in tetrahedral environment are Si atoms; other small open circles are Ta atoms; large open circles are O atoms; large shaded circles are Ba atoms.

TABLE VIII

DISTANCES AND ANGLES IN $\text{Ba}_3\text{Si}_4\text{Ta}_6\text{O}_{26}$

		Distances	
Ba-O(III)	3.06(II) Å	Ta-Ta	3.71(1); 3.82(2); 3.97(2)
Ba-O(IV)	2.84(4); 2.95(4)	O(I)-O(IV)	2.72(4)
Ba-O(V)	3.11(1); 3.42(10)	O(II)-O(III)	2.72(9)
Ta-O(II)	1.94(2)	O(II)-O(IV)	2.88(5)
Ta-O(III)	1.92(3)	O(III)-O(III)	2.60(15)
Ta-O(IV)	2.04(3)	O(III)-O(IV)	2.90(6)
Ta-O(V)	1.99(1)	O(III)-O(V)	2.88(12)
Ta-O(V)	1.99(1)	O(III)-O(V)	2.88(12)
Si-O(I)	1.66(6)	O(IV)-O(IV)	2.60(5); 2.82(6)
Si-O(IV)	1.61(4)	O(IV)-O(V)	2.68(7)
		O(IV)-O(V)	2.68(7)
Angles			
O(I)-Si-O(IV)	111.7(28)°	O(III)-Ta-O(III)	85.1(52)
O(IV)-Si-O(IV)	107.2(31)	O(III)-Ta-O(IV)	93.8(25)
O(II)-Ta-O(III)	89.7(42)	O(IV)-Ta-O(IV)	87.2(18)
O(II)-Ta-O(IV)	92.4(21)		

barium tantalum oxide, $\text{B}_{0.5}\text{TaO}_3$, with the tetragonal tungsten bronze structure, although in this latter compound there are four-membered and five-membered rings as well. Bond lengths and angles (25) are listed in Tables VII and VIII.

Acknowledgments

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